



SCHOTTKY DIODE MODULE TYPES 200A

Features

High Surge Capability
Types Up to 100V V_{RRM}

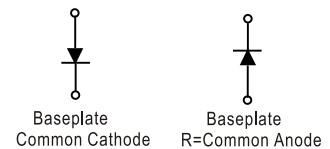
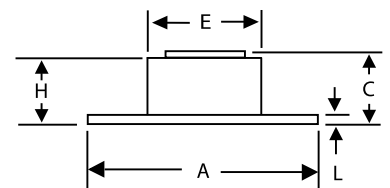
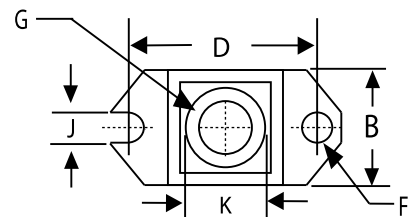
200 Amp Rectifier
20-100 Volts

HALF PACK (D-67)

Maximum Ratings

Operating Temperature: -55°C to $+150^{\circ}\text{C}$
Storage Temperature: -55°C to $+150^{\circ}\text{C}$

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MBRH20020(R)	20V	14V	20V
MBRH20030(R)	30V	21V	30V
MBRH20035(R)	35V	25V	35V
MBRH20040(R)	40V	28V	40V
MBRH20045(R)	45V	32V	45V
MBRH20060(R)	60V	42V	60V
MBRH20080(R)	80V	57V	80V
MBRH200100(R)	100V	70V	100V



Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current (Per pkg)	$I_{F(AV)}$	200A	$TC=125^{\circ}\text{C}$
Peak Forward Surge Current	I_{FSM}	3000A	8.3ms, half sine
Maximum Instantaneous Forward Voltage 20V~45V 50V~60V 80V~100V	V_F	0.70V 0.75V 0.84V	$I_{FM}=200\text{ A}; T_J=25^{\circ}\text{C}$
Maximum Instantaneous Reverse Current At Rated DC Blocking Voltage NOTE (1)	I_R	1mA 10mA 50mA	$T_J = 25^{\circ}\text{C}$ $T_J = 100^{\circ}\text{C}$ $T_J = 150^{\circ}\text{C}$
Maximum Thermal Resistance Junction To Case	$R_{\theta jc}$	0.35 $^{\circ}\text{C}/\text{W}$	

DIMENSIONS					NOTE
DIM	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	1.515	1.560	38.48	39.62	
B	.725	.775	18.42	19.69	
C	.595	.625	15.11	15.88	
D	1.182	1.192	30.02	30.28	
E	.736	.744	18.70	18.90	
F	.152	.160	3.86	4.061	\varnothing
G	1/4 - 20 UNC				
H	.540	.580	13.72	14.73	
J	.156	.160	3.96	4.06	
K	.480	.492	12.20	12.50	\varnothing
L	.120	.130	3.05	3.30	

NOTE :

(1) Pulse Test: Pulse Width 300 μ sec, Duty < 2%



Figure .1-Typical Forward Characteristics

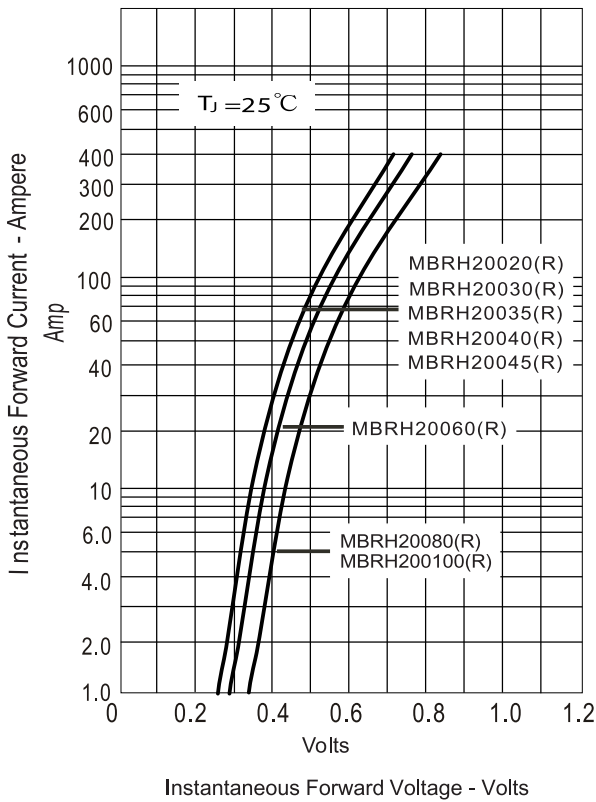


Figure .2- Forward Derating Curve

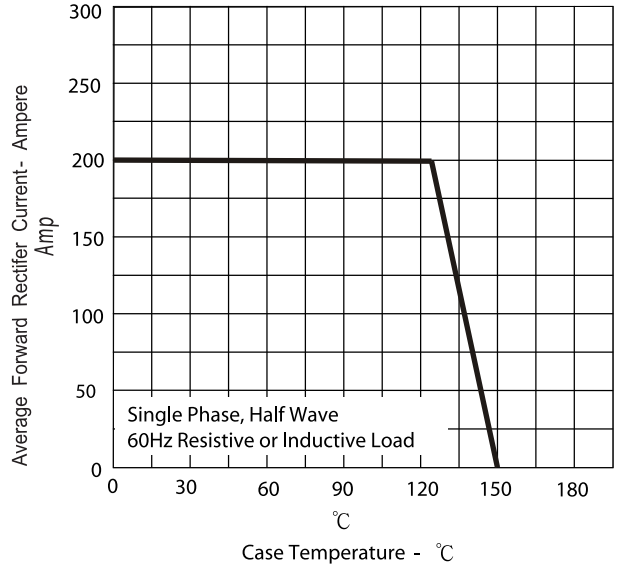


Figure.3-Peak Forward Surge Current

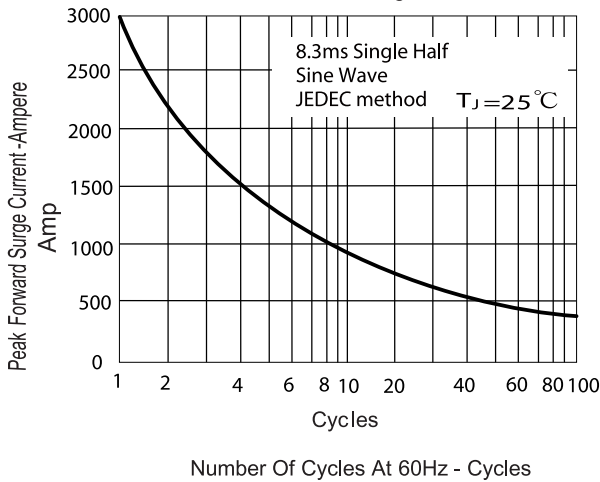


Figure .4- Typical Reverse Characteristics

